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10A, 100V - 200V Trench Schottky Rectifier

FEATURES

- Patented Trench Schottky technology
- Excellent high temperature stability
- Low forward voltage
- Low power loss/ high efficiency
- High forward surge capability
- Compliant to RoHS directive 2011/65/EU and in accordance to WEEE 2002/96/EC
- Halogen-free according to IEC 61249-2-21

TYPICAL APPLICATIONS

Trench Schottky barrier rectifier is designed for high frequency switched mode power supplies such as adapters, lighting, and DC/DC converters.

MECHANICAL DATA

Case: TO-263AB (D²PAK)

Molding compound meets UL 94 V-0 flammability rating

Packing code with suffix "G" means green compound (halogen-free) **Terminal:** Matte tin plated leads, solderable per JESD22-B102

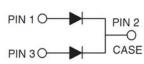
Meet JESD 201 class 1A whisker test

Polarity: As marked

Weight: 1.6 g (approximately)











MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS (T _A = 25°C unless otherwise noted)												
PARAMETER			SYMBOL	TSD10H 100CW		_	SD10H TSD10H 20CW 150CW		_	TSD10H 200CW		UNIT
Maximum repetitive peak reverse voltage			V_{RRM}	100 120 150			50 200		V			
Maximum average forward rectified current	per device per diode		I _{F(AV)}	10 5					А			
Peak forward surge current, 8.3ms single half sine-wave superimposed on rated load per diode			I _{FSM}	100					А			
Voltage rate of change (Rated V _R)			dV/dt	10000						V/µs		
				TYP	MAX	TYP	MAX	TYP	MAX	TYP	MAX	
Instantaneous forward voltage per diode (Note1)	$I_F = 5A$	$T_J = 25^{\circ}C$	V _F	0.62	0.70	0.69	0.79	0.78	0.88	0.81	0.91	· V
	$I_F = 5A$	$T_J = 125^{\circ}C$		0.55	0.63	0.58	0.66	0.64	0.72	0.67	0.75	
Instantaneous reverse current per $T_J = 25$		T _J = 25°C		-	100	-	100	-	100	-	100	μA
diode at rated reverse volta	ge	T _J = 125°C	- I _R	-	15	-	15	1.5	10	1.5	10	mA
Typical thermal resistance per diode			$R_{\theta JC}$	3.2						°C/W		
Operating junction temperature range			T_J	- 55 to +150						°C		
Storage temperature range		T _{STG}	- 55 to +150						°C			

Note 1: Pulse test with pulse width=300µs, 1% duty cycle

Document Number: DS_D0000002



ORDERING INFORMATION						
PART NO.	PACKING CODE	PACKING CODE SUFFIX	PACKAGE	PACKING		
TSD10HXXXCW (Note 1)	C0	G	D ² PAK	50 / Tube		

Note 1: "XXX" defines voltage from 100V (TSD10H100CW) to 200V (TSD10H200CW)

EXAMPLE							
PREFERRED PART NO.	PART NO.		PACKING CODE SUFFIX	DESCRIPTION			
TSD10H150CW C0G	TSD10H150CW	C0	G	Green compound			

RATINGS AND CHARACTERISTICS CURVES

(T_A = 25°C unless otherwise noted)

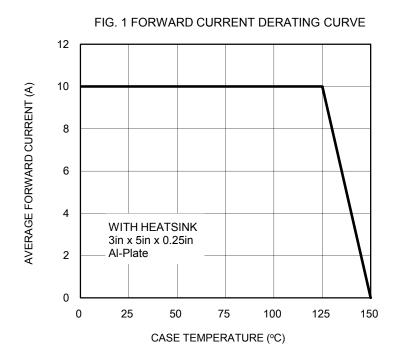
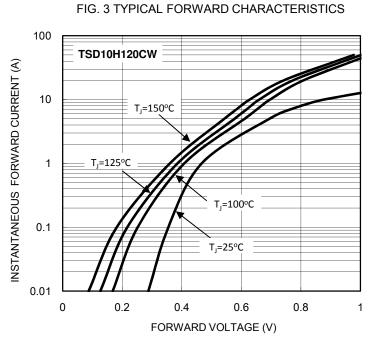


FIG. 2 TYPICAL FORWARD CHARACTERISTICS 100 TSD10H100CW INSTANTANEOUS FORWARD CURRENT (A) 10 T_J=150°C T_J=125°C T₁=100°C 0.1 T_J=25°C 0.01 0.0 0.2 0.4 0.6 8.0 1.0 FORWARD VOLTAGE (V)



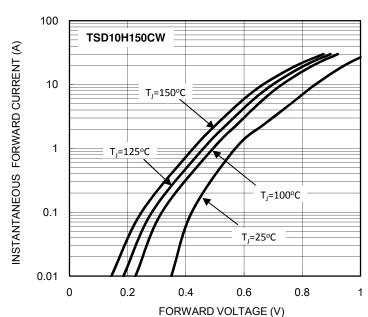


FIG. 4 TYPICAL FORWARD CHARACTERISTICS



FIG. 5 TYPICAL FORWARD CHARACTERISTICS

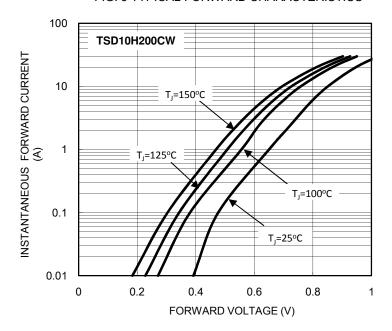


FIG. 6 TYPICAL REVERSE CHARACTERISTICS

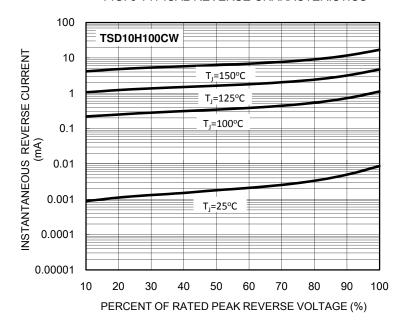


FIG. 7 TYPICAL REVERSE CHARACTERISTICS

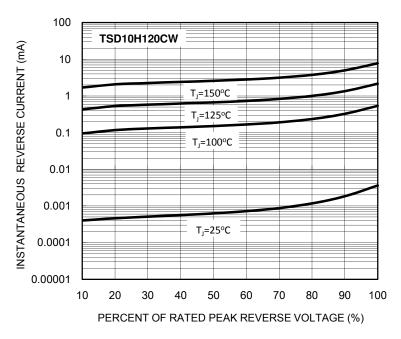


FIG. 8 TYPICAL REVERSE CHARACTERISTICS

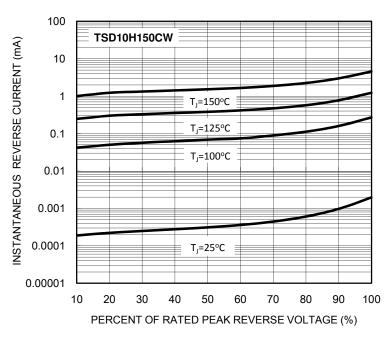


FIG. 9 TYPICAL REVERSE CHARACTERISTICS

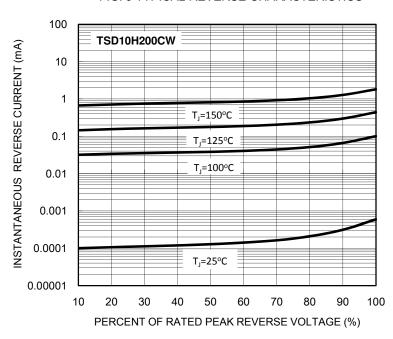
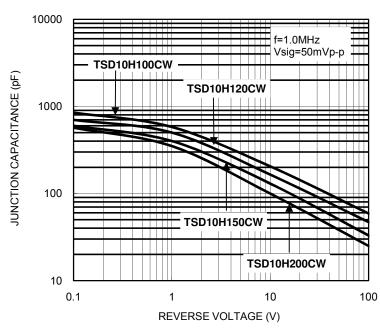


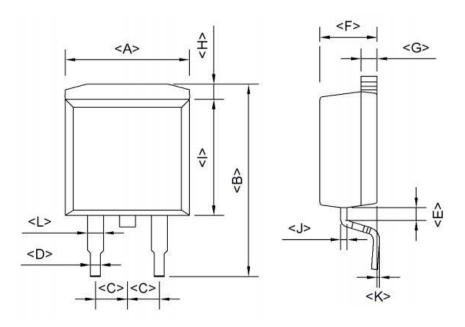
FIG. 10 TYPICAL JUNCTION CAPACITANCE







PACKAGE OUTLINE DIMENSIONS TO-263AB (D²PAK)



DIM.	Unit	(mm)	Unit (inch)				
DIIVI.	Min	Max	Min	Max			
Α	9.600	10.050	0.378	0.396			
В	14.920	15.520	0.587	0.611			
С	2.540	(TYP)	0.100 (TYP)				
D	0.675	0.975	0.027	0.038			
Е	1.778	(TYP)	0.070 (TYP)				
F	4.390	4.790	0.173	0.189			
G	1.150	1.450	0.045	0.057			
Н	1.600	(TYP)	0.063 (TYP)				
I	9.170	9.370	0.361	0.369			
J	0.400	0.600	0.016	0.024			
K	0.254	(TYP)	0.010 (TYP)				
L	1.150	1.550	0.045	0.061			

MARKING DIAGRAM



P/N = Specific Device Code G = Green Compound

YWW = Date Code F = Factory Code

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Taiwan Semiconductor

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